

TOSHIBA CMOS Linear Integrated Circuit Silicon Monolithic

# TCR3DMxxA series

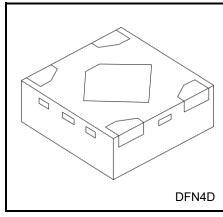
300 mA CMOS Low Drop-Out Regulator with inrush current protection circuit

### 1. Description

The TCR3DMxxA series are CMOS general-purpose single-output voltage regulators with an on/off control input, featuring low dropout voltage, low output noise voltage, fast load transient response and low inrush current.

These voltage regulators are available in fixed output voltages between 1.0 V and 4.5 V and capable of driving up to 300 mA. They feature Overcurrent protection, Thermal shutdown, Inrush current protection circuit and Auto-discharge.

The TCR3DMxxA series is offered in the ultra small plastic mold package DFN4D (1.0 mm x 1.0 mm; t 0.37 mm (typ.)) and has a low dropout voltage of 216 mV (2.5 V output, IOUT = 300 mA) with low output noise voltage of 38  $\mu Vrms$  (2.5 V output). As small ceramic input and output capacitors 1.0  $\mu F$  can be used with the TCR3DMxxA series, these devices are ideal for portable applications that require high-density board assembly such as cellular phones.



Weight: 1.1 mg (typ.)

### 2. Applications

Power IC developed for portable applications

#### 3. Features

- Ultra small package DFN4D (1.0 mm x 1.0 mm; t 0.37 mm (typ.))
- Wide range output voltage line up (Vout = 1.0 to 4.5 V)
- Low dropout voltage

 $V_{DO}$  = 175 mV (typ.) at 3.3 V output,  $I_{OUT}$  = 300 mA

 $V_{DO}$  = 216 mV (typ.) at 2.5 V output,  $I_{OUT}$  = 300 mA

 $V_{DO} = 297 \text{ mV (typ.)}$  at 1.8 V output,  $I_{OUT} = 300 \text{ mA}$ 

- Low output noise voltage (VNO =  $38 \mu V_{rms}$  (typ.) at  $10Hz \le f \le 100kHz$ )
- High ripple rejection ratio (72 dB (typ.) at 2.5 V output, I<sub>OUT</sub> = 10 mA, f = 1 kHz)
- Fast load transient response (±80 mV (typ.) at 2.5 V output, I<sub>OUT</sub> = 1 mA ⇔ 300 mA)
- Overcurrent protection
- Thermal shutdown
- Inrush current protection circuit
- Auto-discharge
- Pull down connection between CONTROL and GND
- Ceramic capacitors can be used (C<sub>IN</sub> = 1.0 μF, C<sub>OUT</sub> = 1.0 μF)

Start of commercial production 2023-11



### 4. Absolute Maximum Ratings (Note) (Ta = 25 °C)

Characteristics	Symbol	Rating	Unit
Input voltage	V <sub>IN</sub>	-0.3 to 6.0	V
Control voltage	Vст	-0.3 to 6.0	V
Output voltage	Vout	-0.3 to V <sub>IN</sub> + 0.3 ≤ 6.0	٧
Power dissipation	PD	420 (Note1)	mW
Junction temperature	Tj	150	°C
Storage temperature range	T <sub>stg</sub>	−55 to 150	°C

Note:

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

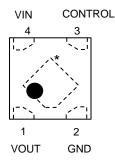
Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note1: Rating at mounting on a board

Glass epoxy(FR4) board dimension: 40 mm x 40 mm x 1.6mm, both sides of board. Metal pattern ratio: a surface approximately 50%, the reverse side approximately 50 %

Through hole hall: diameter 0.5 mm x 24 pcs

### 5. Pin Assignment (Top view)



<sup>\*</sup>Center electrode should be connected to GND or Open

### 6. Operating Ranges

Characteristics	Symbol		Rating		Unit
Input voltage	VIN		1.5 to 5.5	(Note 2)	V
Control voltage	Vст		0 to 5.5		V
Output voltage	Vout		1.0 to 4.5		V
Output current	lout	DC	300		mA
Operation Temperature	Topr		-40 to 85		°C
Output Capacitance	Cout	≥ 1.0			μF
Input Capacitance	CIN	≥ 1.0			μF

Note 2: Please refer to Dropout Voltage and use it within Absolute Maximum Ratings Junction temperature and Operation Temperature Ranges.



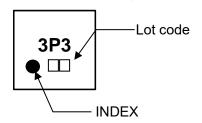
# 7. List of Products Number, Output voltage and Marking

Product No.	Output voltage (V)	Marking	Product No.	Output voltage (V)	Marking
TCR3DM10A	1.0	1P0	TCR3DM26A*	2.6	2P6
TCR3DM105A	1.05	1PA	TCR3DM27A*	2.7	2P7
TCR3DM11A	1.1	1P1	TCR3DM28A	2.8	2P8
TCR3DM115A*	1.15	1PB	TCR3DM285A*	2.85	2PD
TCR3DM12A	1.2	1P2	TCR3DM29A*	2.9	2P9
TCR3DM13A*	1.3	1P3	TCR3DM2925A*	2.925	2PH
TCR3DM135A*	1.35	1PD	TCR3DM30A*	3.0	3P0
TCR3DM14A*	1.4	1P4	TCR3DM31A*	3.1	3P1
TCR3DM15A	1.5	1P5	TCR3DM32A*	3.2	3P2
TCR3DM16A*	1.6	1P6	TCR3DM33A	3.3	3P3
TCR3DM175A*	1.75	1PE	TCR3DM35A*	3.5	3P5
TCR3DM18A	1.8	1P8	TCR3DM36A*	3.6	3P6
TCR3DM1825A*	1.825	1PF	TCR3DM41A*	4.1	4P1
TCR3DM185A*	1.85	1PG	TCR3DM42A*	4.2	4P2
TCR3DM19A*	1.9	1P9	TCR3DM45A	4.5	4P5
TCR3DM25A	2.5	2P5	_	_	_

<sup>\*</sup> Please contact your local Toshiba representative if you are interested in products with \* sign.

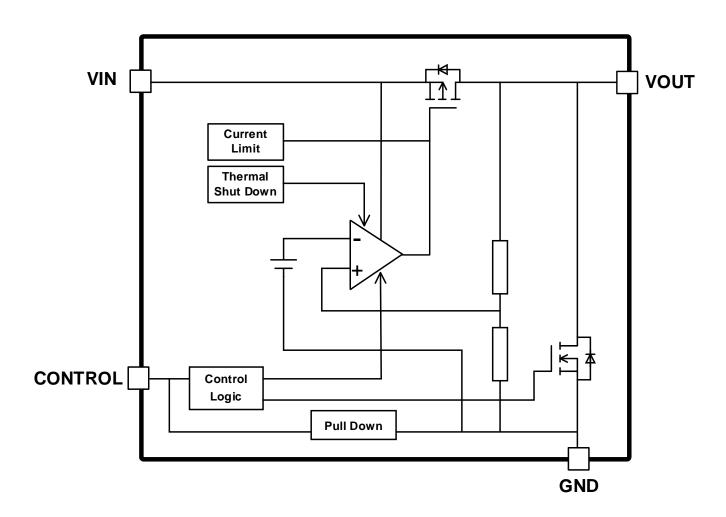
### **Top Marking (Top view)**

Example: TCR3DM33A (3.3 V output)





# 8. Block Diagram





#### 9. Electrical Characteristics

(Unless otherwise specified,  $V_{IN} = V_{OUT} + 1.0 \text{ V}$ ,  $C_{IN} = 1.0 \mu\text{F}$ ,  $C_{OUT} = 1.0 \mu\text{F}$ )

Characteristics	Symbol	I Test Condition		T <sub>j</sub> = 25 °C			T <sub>j</sub> = -40 to 85 °C (Note 8)		Unit
				Min	Тур.	Max	Min	Max	
		IOUT = 50 mA	Vout < 1.8 V	-18	_	+18	_	_	mV
Output voltage accuracy	Vout	V <sub>IN</sub> = V <sub>OUT</sub> + 1.0 V (Note 3)	1.8V ≤ V <sub>OUT</sub>	-1.0	_	+1.0	_	_	%
Line regulation	Reg·line	$V_{OUT} + 0.5 V \le V_{IN} \le 5.$ $I_{OUT} = 1 \text{ mA}$	5 V	_	1	_	_	_	mV
Load regulation	Reg·load	1 mA ≤ I <sub>OUT</sub> ≤ 300 mA		_	18	_	_	52	mV
Quiescent current	I <sub>B</sub> (ON)	I <sub>OUT</sub> = 0 mA V <sub>IN</sub> = 5.5 V (Note 5)	V <sub>OUT</sub> = 4.5 V	_	86	_	_	159	μA
Stand-by current	IB (OFF)	VCT = 0 V, VIN = 5.5 V	(Note 5)	_	0.1	_	_	1	μA
Control pull down current	Іст	_		_	0.1	_	_	0.2	μA
	V <sub>DO</sub>		V <sub>OUT</sub> = 1.8 V	_	297	335	_	389	mV
Drop out voltage (Note 0)		I <sub>OUT</sub> = 300 mA	V <sub>OUT</sub> = 2.5 V	_	216	262	_	296	mV
Drop-out voltage (Note 9)			V <sub>OUT</sub> = 3.3 V	_	175	206	_	242	mV
			V <sub>OUT</sub> = 4.5 V	_	148	179	_	231	mV
Output noise voltage	V <sub>NO</sub>	I <sub>OUT</sub> = 10 mA 10 Hz ≤ f ≤ 100 kHz, Ta = 25 °C (Note 4)		_	38	_	_	_	μV <sub>rms</sub>
			f = 100 Hz	_	75	_	_	-	dB
		V <sub>IN</sub> = 3.5 V V <sub>OUT</sub> = 2.5 V I <sub>OUT</sub> = 10 mA, V <sub>IN</sub> Ripple = 500 mV <sub>p-p</sub> , Ta = 25 °C (Note 4)	f = 1 kHz	_	72	_	_	_	
Ripple rejection ratio	R.R.		f = 10 kHz	-	54	_	_	_	
			f = 100 kHz	_	48	_	_	_	
	1a = 25 C (Note 4)		f = 1 MHz	-	55	_	_	_	1
1 1 (	4) (	IOUT = 1 mA → 300 mA	(Note 4) (Note 6)	_	-80	_	_	_	>/
Load transient response		I <sub>OUT</sub> = 300 mA → 1 mA	T = 300 mA → 1 mA (Note 4) (Note 6)		+80	_	_	_	mV
Output current limit	I <sub>CL</sub>	Vout = Vout(NOM)*90 % (Note 7)		-	_	_	320	650	mA
The arms of the state of the st	TSDH	T <sub>J</sub> rising		_	160	_	_	_	°C
Thermal shutdown threshold	T <sub>SDL</sub>	T <sub>J</sub> falling		_	130	_	_	_	°C
Control voltage (HIGH)	Vстн	Control pin input voltage "HIGH"			_	_	0.8	5.5	V
Control voltage (LOW)	VCTL	Control pin input voltage "LOW"			_	_	0	0.4	V
Discharge on resistance	RsD	(Note 4)		_	45	_	_	_	Ω

Note 3: stable state with fixed I<sub>OUT</sub> condition

Note 4: Vout = 2.5 V

Note 5: except Control pull down current (I<sub>CT</sub>)

Note 6:  $t_r = t_f = 1.0 \mu s$  (Defined when 10 % to 90 % is 0.8  $\mu s$ )

Note 7: Pulse measurement

Note 8: This parameter is warranted by design.

Note 9: V<sub>DO</sub> = V<sub>IN1</sub> - (V<sub>OUT1</sub> x 0.97)

 $V_{OUT1}$  is the output voltage when  $V_{IN} = V_{OUT} + 1.0 \text{ V}$ .

V<sub>IN1</sub> is the input voltage at which the output voltage becomes 97 % of V<sub>OUT1</sub> after gradually decreasing the input voltage.



# 10. Drop-out voltage table

(IOUT = 300 mA, CIN = 1.0  $\mu$ F, COUT = 1.0  $\mu$ F)

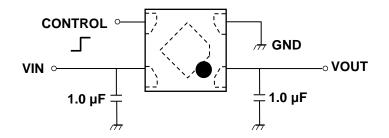
Output voltages	Symbol	T <sub>j</sub> = 25 °C			T <sub>j</sub> = -40 (Not	Unit	
		Min	Тур.	Max	Min	Max	
1.0 V, 1.05 V		_	642	738	_	790	
1.1 V, 1.15 V		_	566	666	_	716	
1.2 V		_	500	592	_	644	
1.3 V		_	456	535	_	590	
1.35V, 1.4 V		_	434	506	_	563	
1.5 V ≤ V <sub>OUT</sub> < 1.8 V		_	367	419	_	481	1 ,,
1.8 V ≤ V <sub>OUT</sub> < 1.9 V	VIN-VOUT	_	297	335	_	389	mV
1.9 V ≤ V <sub>OUT</sub> < 2.5 V		_	277	309	_	365	
2.5 V ≤ V <sub>OUT</sub> < 2.8 V		_	216	262	_	296	
2.8 V ≤ V <sub>OUT</sub> < 3.2 V		_	196	233	_	268	
3.2 V ≤ V <sub>OUT</sub> < 3.6 V		_	179	211	_	247	
3.6 V ≤ V <sub>OUT</sub> ≤ 4.5 V		_	168	199	_	240	

Note 10: This parameter is guaranteed by design.



### 11. Application Note

#### 11.1. Recommended Application Circuit



CONTROL voltage	Output voltage
HIGH	ON
LOW	OFF
OPEN	OFF

The figure above shows the recommended configuration for using a Low-Dropout regulator. Insert a capacitor at Vout and Vin pins for stable input/output operation. (Ceramic capacitors can be used).

#### 11.2. Power Dissipation

Board-mounted power dissipation ratings for TCR3DMxxA series are available in the Absolute Maximum Ratings table. Power dissipation is measured on the board condition shown below.

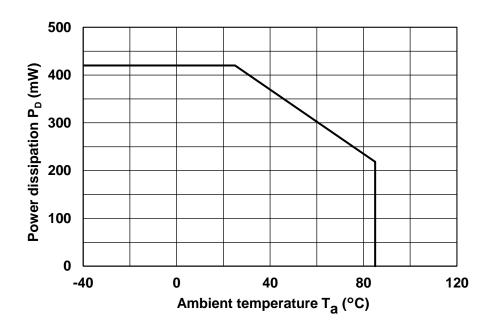
[The Board Condition]

Board material: Glass epoxy(FR4)

Board dimension: 40 mm x 40 mm (both sides of board), t = 1.6 mm

Metal pattern ratio: a surface approximately 50%, the reverse side approximately 50 %

Through hole: diameter 0.5 mm x 24 pcs





#### 11.3. Attention in Use

#### Output Capacitors

Ceramic capacitors can be used for these devices. However, because of the type of the capacitors, there might be unexpected thermal features. Please consider application condition for selecting capacitors. And Toshiba recommend ceramic capacitor.

#### Mounting

The long distance between IC and output capacitor might affect phase assurance by impedance in wire and inductor. For stable power supply, output capacitor need to mount near IC as much as possible. Also VIN and GND pattern need to be large and make the wire impedance small as possible.

#### Permissible Loss

Please have enough design patterns for expected maximum permissible loss. And under consideration of surrounding temperature, input voltage, and output current etc., we recommend proper dissipation ratings for maximum permissible loss; in general maximum dissipation rating is 70 to 80 %.

Over current Protection and Thermal shut down function

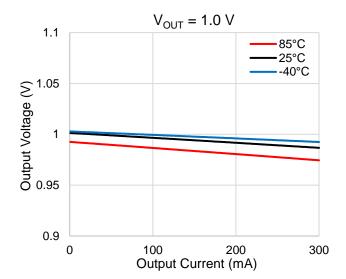
Over current protection and Thermal shut down function are designed in these products, but these are not designed to constantly ensure the suppression of the device within operation limits. Depending on the condition during actual usage, it could affect the electrical characteristic specification and reliability. Also note that if output pins and GND pins are not completely shorted out, these products might be break down. When using these products, please read through and understand the concept of dissipation for absolute maximum ratings from the above mention or our 'Semiconductor Reliability Handbook'. Then use these products under absolute maximum ratings in any condition. Furthermore, Toshiba recommend inserting failsafe system into the design.

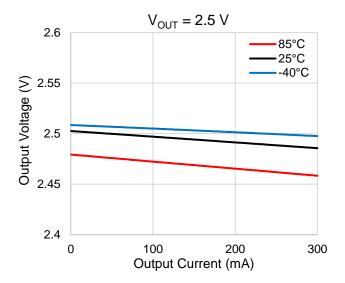


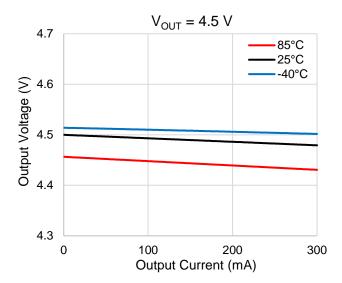
# 12. Representation Typical Characteristics (Note)

#### 12.1. Output Voltage vs. Output Current

 $(V_{IN} = V_{OUT} + 1.0 V)$ 

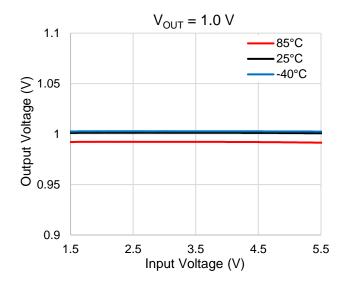


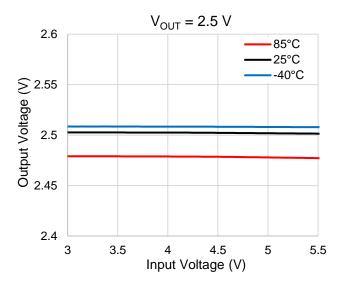


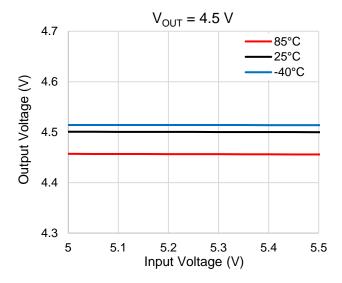




# 12.2. Output Voltage vs. Input Voltage (lout = 1 mA)

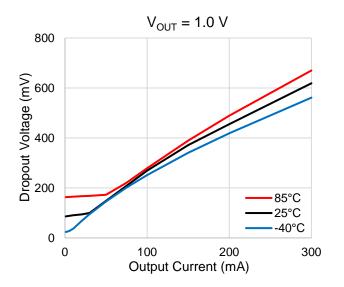


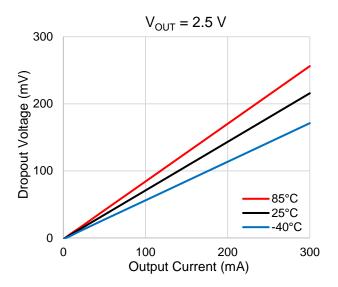


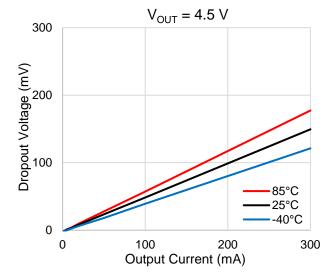




### 12.3. Dropout Voltage vs. Output Current

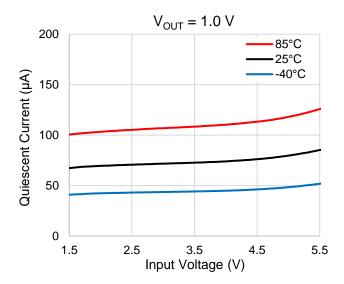


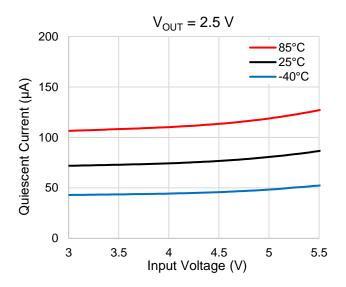


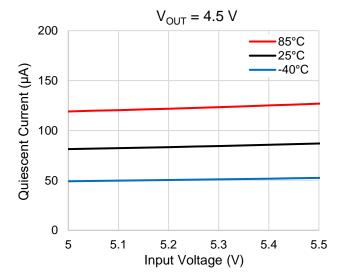




# 12.4. Quiescent Current vs. Input Voltage (I<sub>OUT</sub> = 0 mA)



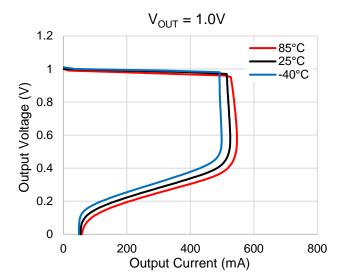


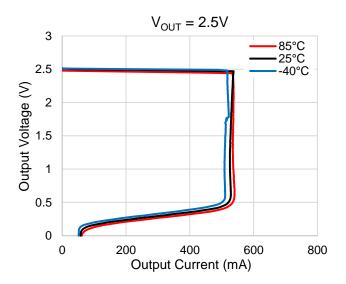


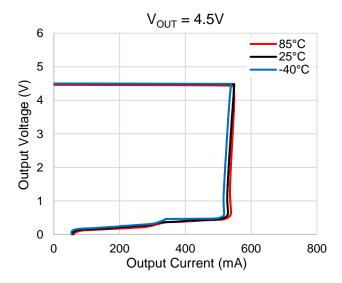


### 12.5. Output Current Limit

 $(V_{IN} = V_{OUT} + 1.0 V)$ 



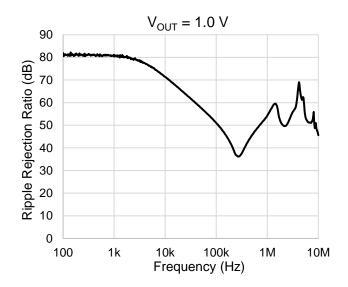


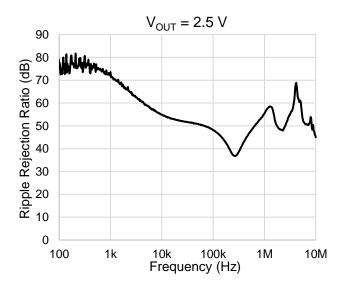


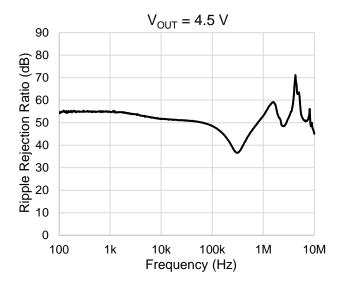


#### 12.6. Ripple rejection Ratio vs. Frequency

(CIN = none, COUT = 1.0  $\mu$ F, VIN = VOUT + 1.0 V, VIN Ripple = 500 mV<sub>p-p</sub>, louT = 10 mA, Ta = 25°C)



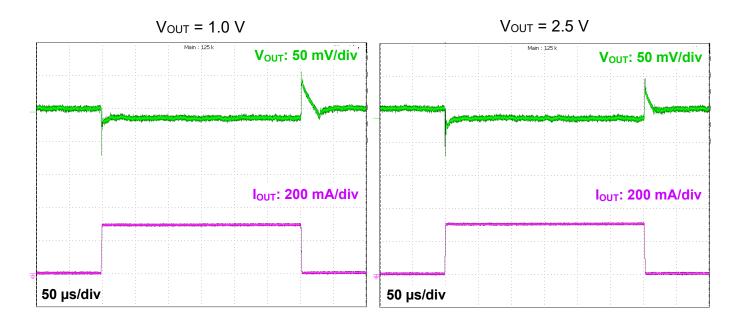


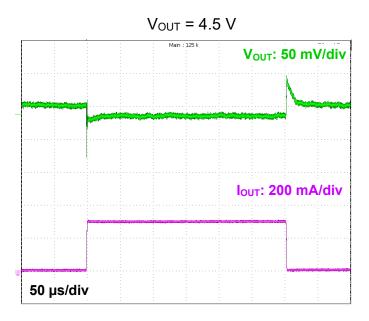




#### 12.7. Load Transient Response

(CIN = 1.0  $\mu$ F, COUT = 1.0  $\mu$ F, VIN = VOUT + 1.0 V, IOUT = 1 mA  $\Leftrightarrow$  300 mA, tr = 1.0  $\mu$ S, tf = 1.0  $\mu$ S, Ta = 25°C)







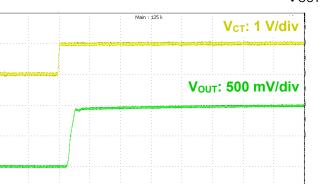
#### 12.8. ton / toff Response

(Cin = 1.0  $\mu$ F, Cout = 1.0  $\mu$ F, Vin = Vout + 1.0 V, Vct = 0 V  $\Leftrightarrow$  1.0 V, Ta = 25°C)

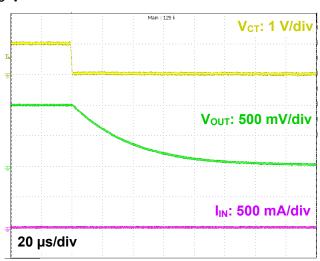
I<sub>IN</sub>: 500 mA/div

#### ● I<sub>OUT</sub> = 0 mA

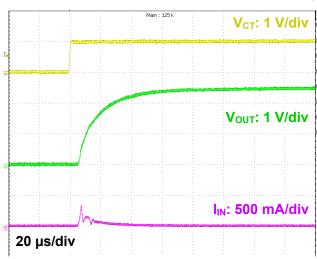
20 µs/div

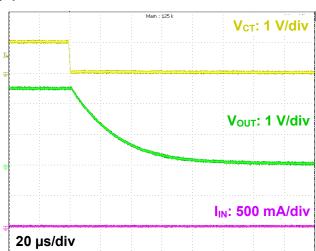




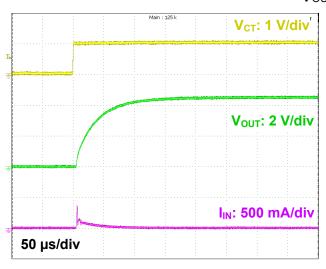


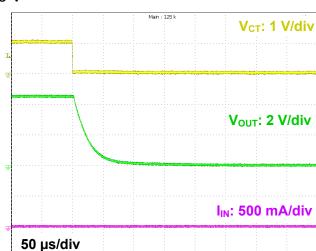




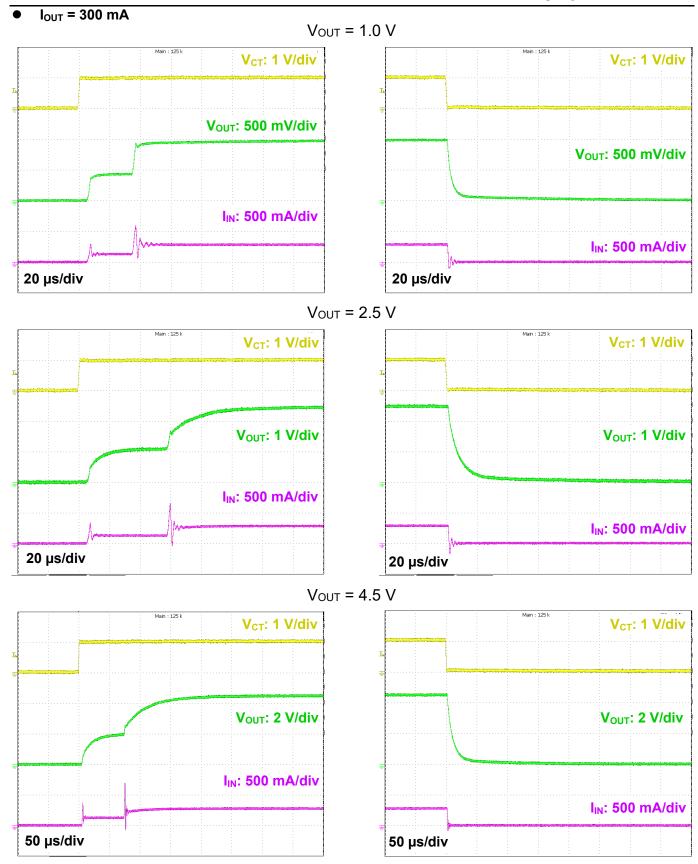


#### $V_{OUT} = 4.5 V$







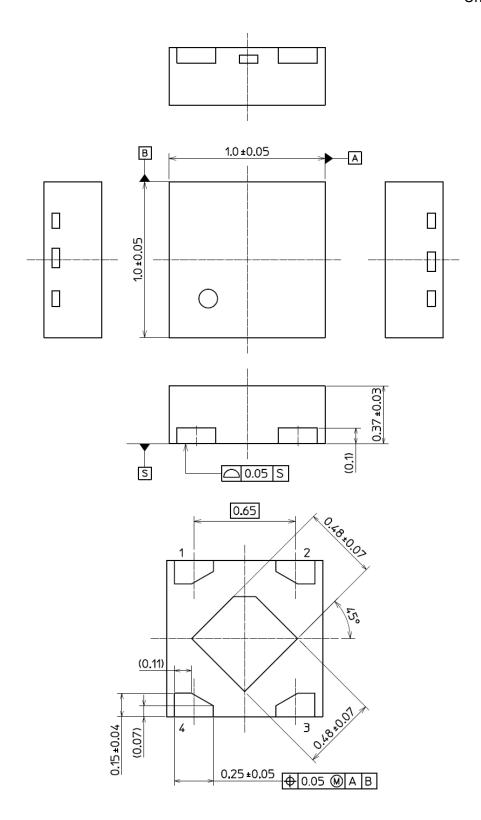




# 13. Package Information

DFN4D

Unit: mm

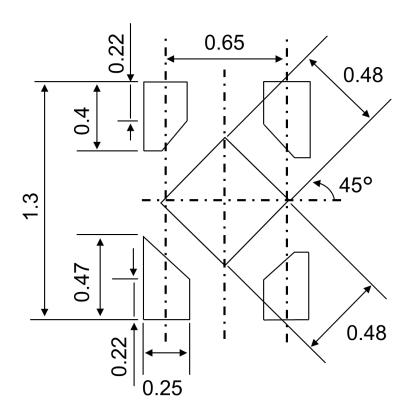


Weight: 1.1 mg (typ.)



# 14. Land Pattern Dimensions (for reference only)

Unit: mm





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